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| UTILITY PATENT APPLICATION TRANSMITTAL <small>(Only for new nonprovisional applications under 37 CFR 1.53(b))</small> | Attorney Docket No. | 0557-4969-2 |
| | First Inventor or Application Identifier | Tomohiro NAKAJIMA |
| | Title | MULTIBEAM SCANNING APPARATUS |

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| APPLICATION ELEMENTS <small>See MPEP chapter 600 concerning utility patent application contents</small> | ADDRESS TO: Assistant Commissioner for Patents Box Patent Application Washington, DC 20231 |
| <p>1. <input checked="" type="checkbox"/> Fee Transmittal Form (e.g. PTO/SB/17) (Submit an original and a duplicate for fee processing)</p> <p>2. <input checked="" type="checkbox"/> Specification Total Pages 38</p> <p>3. <input checked="" type="checkbox"/> Drawing(s) (35 U.S.C. 113) Total Sheets 5</p> <p><input checked="" type="checkbox"/> Oath or Declaration Total Pages </p> <p>a. <input type="checkbox"/> Newly executed (original or copy)</p> <p>b. <input type="checkbox"/> Copy from a prior application (37 C.F.R. §1.63(d)) <small>(for continuation/divisional with box 15 completed)</small></p> <p>i. <input type="checkbox"/> DELETION OF INVENTOR(S) <small>Signed statement attached deleting inventor(s) named in the prior application, see 37 C.F.R. §1.63(d)(2) and 1.33(b).</small></p> <p>5. <input type="checkbox"/> Incorporation By Reference <small>(usable if box 4B is checked)</small> <small>The entire disclosure of the prior application, from which a copy of the oath or declaration is supplied under Box 4B, is considered to be part of the disclosure of the accompanying application and is hereby incorporated by reference therein.</small></p> | ACCOMPANYING APPLICATION PARTS <p>6. <input type="checkbox"/> Assignment Papers (cover sheet & document(s))</p> <p>7. <input type="checkbox"/> 37 C.F.R. §3.73(b) Statement <input type="checkbox"/> Power of Attorney <small>(when there is an assignee)</small></p> <p>8. <input type="checkbox"/> English Translation Document <small>(if applicable)</small></p> <p>9. <input type="checkbox"/> Information Disclosure Statement (IDS)/PTO-1449 <input type="checkbox"/> Copies of IDS Citations</p> <p>10. <input type="checkbox"/> Preliminary Amendment</p> <p>11. <input checked="" type="checkbox"/> White Advance Serial No. Postcard</p> <p>12. <input type="checkbox"/> Small Entity Statement(s) <input type="checkbox"/> Statement filed in prior application. Status still proper and desired.</p> <p>13. <input type="checkbox"/> Certified Copy of Priority Document(s) <small>(if foreign priority is claimed)</small></p> <p>14. <input checked="" type="checkbox"/> Other: Notice of Priority, List of Inventor's Name and Address</p> |
| <p>15. If a CONTINUING APPLICATION, check appropriate box, and supply the requisite information below:</p> <p><input type="checkbox"/> Continuation <input type="checkbox"/> Divisional <input type="checkbox"/> Continuation-in-part (CIP) of prior application no.: Prior application information: Examiner: Group Art Unit:</p> | |
| <p>16. Amend the specification by inserting before the first line the sentence:</p> <p><input type="checkbox"/> This application is a <input type="checkbox"/> Continuation <input type="checkbox"/> Division <input type="checkbox"/> Continuation-in-part (CIP) of application Serial No. Filed on</p> <p><input type="checkbox"/> This application claims priority of provisional application Serial No. Filed</p> | |
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IN RE APPLICATION OF: Tomohiro NAKAJIMA

FILING DATE: Herewith

FOR: MULTIBEAM SCANNING APPARATUS

LIST OF INVENTOR'S NAME AND ADDRESS

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SIR:

Listed below are the name and address of the inventor for the above-identified patent application.


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Tokyo, Japan

A declaration containing all the necessary information will be submitted at a later date.

Respectfully Submitted,

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SPECIFICATION

TO ALL WHOM IT MAY CONCERN:

BE IT KNOWN THAT I, TOMOHIRO NAKAJIMA, a
citizen of Japan residing at Tokyo, Japan have
invented certain new and useful improvements in

MULTIBEAM SCANNING APPARATUS

of which the following is a specification:-

TITLE OF THE INVENTION

MULTIBEAM SCANNING APPARATUS

BACKGROUND OF THE INVENTION

1. Field of the Invention

5 The present invention relates to an optical scanning apparatus used in a write system of a digital copying machine, a laser beam printing machine or the like. More particularly, the present invention is concerned with a multibeam scanning apparatus capable of
10 simultaneously scanning a scanned surface such as a photosensitive member with multiple light beams so that the recording rate can be increased.

2. Description of the Related Art

Conventionally, a method for increasing the
15 revolution speed of a polygonal mirror is known as means for increasing the recording rate of the optical scanning apparatus used in the write system. However, the above method results in an increased load on a motor for driving the polygonal mirror. The increased load
20 degrades durability of the optical scanning apparatus, and causes noise and vibration. Eventually, improvement in the recording rate is limited.

A multibeam scanning apparatus has been proposed which simultaneously records a plurality of
25 lines with a plurality of light beams formed

simultaneously. For example, Japanese Laid-Open Patent Application No. 6-331913 discloses that light beams emitted by a light source made up of a plurality of semiconductor laser diodes are combined by means of a beam splitter. However, the proposed method needs a fine control of the optical axes of the light beams. Such a fine control needs a complex adjustment mechanism and cumbersome adjustment work.

Another multibeam scanning apparatus has been proposed which as a multibeam light source, in which a plurality of semiconductor laser diodes and a coupling lens are incorporated into a module and beams emitted by the laser diodes are made closer to each other and are then combined by a beam combining means. The above multibeam light source has a simple structure that can be assembled with ease, and makes it possible to easily adjust a sub scan pitch.

The above-mentioned method using the laser diodes and the beam splitter has a disadvantage in that a housing or optical components forming the light sources may be deformed due to an environment change. Such a deformation results in a variation in the attitude of the optical unit itself, and a positional displacement between the semiconductor lasers and the coupling lens. Thus, the sub scan pitch on the scanned

surface is liable to be varied. The above disadvantage needs a mechanism for measuring the sub scan pitch, and another mechanism for correcting the sub scan pitch based on the sub scan pitch thus measured.

5 Particularly, Japanese Laid-Open Patent Application No. 6-331913 shows a feedback correction in which a prism is used for each beam in order to finely adjust the optical axis and thus cause the light beams to travel in the correct direction. However, such a feedback correction
10 is implemented by a complex structure and is thus expensive.

In contrast, the proposal using the module provides the following advantages. The semiconductor laser diodes and the coupling lens are integrally
15 supported by an identical base member, and the beams are emitted in the main scanning direction at given angular intervals. With the above structure, it is possible to adjust the sub scan pitch by merely adjusting the revolution of the entire light source unit and assemble
20 the apparatus easily. In this regard, the semiconductor laser diodes may be arranged close to each other in order to omit the beam combining means.

However, in any proposal using the modules, the beam emitting positions are offset from the optical
25 axis (rotational axis). Thus, the adjustment of the sub

scan pitch varies the beam emitting points, so that the light beams may be inclined. It is thus required to adjust the optical axis with a high precision sufficient to hold down a fine revolution.

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SUMMARY OF THE INVENTION

It is an object of the present invention to provide a less-expensive multibeam scanning apparatus having a simple structure which can easily be assembled.

10

Another object of the present invention is to provide a multibeam scanning apparatus capable of realizing high-rate, high-density recording without increasing the size of the polygonal mirror.

15

The above objects of the present invention are achieved by a multibeam scan apparatus comprising: a light source having semiconductor laser diodes and coupling lenses arranged in a main scan direction, the semiconductor laser diodes being positioned so that light beams emitted by the semiconductor laser diodes

20

substantially cross each other at a point; a light beam restricting unit shaping the light beams from the laser diodes through the coupling lenses so that the light beams have a given spot size, the light beam restricting unit being positioned close to the point; a polygonal

25

mirror; and a scan lens causing the light beams

reflected by the polygonal mirror to form images on a scanned surface.

The above objects of the present invention are also achieved by a multibeam scan apparatus comprising:

5 a light source having a semiconductor laser diode array of light-emitting sources, and a coupling lens, the light-emitting sources being arranged in a main scan direction; a convergent unit causing the light beams to converge in the main scan direction; a light beam

10 restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close to a position at which the light beams cross each other due to a function of the convergent unit; a polygonal mirror; and a scan lens causing the

15 light beams reflected by the polygonal mirror to form images on a scanned surface.

The above objects of the present invention are also achieved by a multibeam scan apparatus comprising:

a light source emitting light beams, outgoing beam

20 directions in which the light beams travel being arranged so as to cross each other; a deflection unit deflecting the light beams; and an optical unit causing the light beams from the deflection unit to form images on a scanned surface.

25 The above-mentioned objects of the present

invention are also achieved by a multibeam scan apparatus comprising: a light source having semiconductor laser diodes and coupling lenses arranged in a main scan direction, the semiconductor laser diodes
5 being positioned so that outgoing beam directions in which light beams emitted by the semiconductor laser diodes travel cross each; a deflection unit deflecting the light beams; and an optical unit causing the light beams to form images on a scanned surface.

10 The above objects of the present invention are also achieved by a multibeam scan apparatus comprising: a light source having a semiconductor laser diode array of light-emitting sources formed in a monolithic formation, and a coupling lens, the light-emitting
15 sources being arranged in a main scan direction; a convergent unit causing the light beams to converge in the main scan direction; a light beam restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close
20 to a position at which the light beams cross each other due to a function of the convergent unit; a deflection unit deflecting the light beams; and a scan lens causing the light beams deflected by the deflection unit to form images on a scanned surface.

25

BRIEF DESCRIPTION OF THE DRAWINGS

Other objects, features and advantages of the present invention will become more apparent from the following detailed description when read in conjunction
5 with the accompanying drawings, in which:

Fig. 1 is an exploded perspective view of a light source of a multibeam scan apparatus according to a first embodiment of the present invention;

Fig. 2 is a cross-sectional view taken along a
10 main scan direction;

Fig. 3 is a perspective view of light beam shaping by an aperture;

Fig. 4 is a perspective view of an overall structure of the multibeam scan apparatus according to
15 the first embodiments of the present invention;

Figs 5A and 5B are diagrams of an arrangement in which a light beam restricting unit is incorporated into a reflection surface of a polygonal mirror;

Figs. 6A and 6B are diagrams of a variation of
20 the arrangement shown in Figs. 5A and 5B;

Fig. 7 is a cross-sectional view of a light source according to a second embodiment of the present invention;

Fig. 8 is a cross-sectional view of a light
25 source according to a third embodiment of the present

invention; and

Fig. 9 is a cross-sectional view of a light source according to a fourth embodiment of the present invention.

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DESCRIPTION OF THE PREFERRED EMBODIMENTS

A description will now be given, with reference to Figs. 1 through 5, of a first embodiment of the present invention. Fig. 1 shows a light source of a multibeam scanning apparatus using two semiconductor laser diodes, and Fig. 2 is a cross-sectional view thereof taken along a main scan direction Y shown in Fig. 1.

Referring to Fig. 1, two semiconductor laser diodes 1 and 2 are respectively inserted, with a pressure, into fitting holes 3a and 3b (see Fig. 2) formed on a back side of a base member made of aluminum die-cast and arranged side by side at an interval of 8 mm in the main scan direction Y. The distance of 8 mm allows coupling lenses 4 and 5 to be arranged side by side. The coupling lenses 4 and 5 are placed into holes integral with the fitting holes 3a and 3b, and are fixed therein by UV hardening resin. The coupling lenses 4 and 5 are positioned as follows. The positions of the coupling lenses 4 and 5 are adjusted in the X direction

so that the light beams respectively emitted by the semiconductor laser diodes 1 and 2 are changed to light beams having a given divergence. Further, the positions of the coupling lenses 4 and 5 are adjusted in the Y and Z directions so that the light beams travel in the given beam emitting directions. A light source 6 is formed by the semiconductor laser diodes 1 and 2, the base member 3, and the coupling lenses 4 and 5.

As shown in Fig. 2, the fitting holes 3a and 3b are formed so as to have a given angle with respect to an optical axis C, and the coupling lenses 4 and 5 are arranged so that the axes thereof are inclined at the given angle.

The embodiment of the present invention shown in Figs. 1 and 2 have the fitting holes 3a and 3b that are inclined. Alternatively, it is possible to position the coupling lenses 4 and 5 in an eccentric fashion with respect to the axes of the semiconductor laser diodes 1 and 2 rather than tilting the fitting holes 3a and 3b.

The base member 3 is fixed to a holding member 7 by screws 8. A hollow cylindrical member 7a of the holding member 7 is fitted into a fitting hole 9a formed in a sidewall 9 formed in an optical housing so that the axis of the holding member 7 aligns with that of the sidewall 9 of the optical housing. A spring 10 is

provided around another cylindrical portion of the holding member 7 extending from the hollow cylindrical portion 7a. A ring-shaped press member 11 is engaged with flange portions 7b of the holding member 7, so that
5 the spring 10 is sandwiched between the sidewall 9 and the ring-shaped press member 11. A bent portion 10a of the spring extending along the optical axis is engaged with a hole 11a formed in the press member 11. An arm portion 10b of the spring 10 is engaged with a
10 projection 9b of the sidewall 9. Thus, the spring 10 generates a clockwise torsion. A rotary movement blocking protrusion 7c formed in the holding member 7 is brought into contact with an adjustment screw 12, which accomplishes a rotational adjustment about the optical
15 axis. The adjustment screw 12 is held by a screw (not shown) formed in the sidewall 9.

The two light beams B1 and B2 respectively emitted by the light source 6 thus configured pass through an aperture 13 shown in Fig. 3. The aperture 13
20 is located at a crossing position P at which the light beams B1 and B2 cross. The aperture 13 functions as means for restricting the spot sizes of the light beams B1 and B2. More particularly, the aperture 13 shapes the light beams B1 and B2 so as to have a given spot
25 shape of a predetermined size. Preferably, the aperture

13 is located in the optical path starting with the light source 6 and ending with the polygonal mirror, and is located close to the polygonal mirror.

A description will be given of a formation in which the light beams B1 and B2 are crossed on the reflection (deflection) surfaces of the polygonal mirror, which acts as a beam deflecting means. Fig. 4 shows a structure of the multibeam scanning apparatus using the light source 6 shown in Fig. 1. The formation shown in Fig. 4 is arranged so that the light beams B1 and B2 emitted by the semiconductor laser diodes 1 and 2 cross each other on reflection surfaces 14a of the polygonal mirror 14 and the size of each reflection surface 14a is set equal to the size of the aperture 13. The polygonal mirror 14 shown in Fig. 4 has 10 reflection surfaces.

The light beams B1 and B2 emitted through the coupling lenses 4 and 5 of the light source 6 pass through a cylindrical lens 15, and is then reflected by a mirror 16, so that the light beams B1 and B2 travel in an oblique, upward direction. At that time, the light beams B1 and B2 emitted by the light source 6 are changed to divergence beams or fluxes. Thus, as shown in Fig. 5A, the cross sections or spots of the light beams B are made larger than the size M of each reflection surface of the polygonal mirror 14. Thus,

light beams B1' and B2' traveling from the polygonal mirror 14 are shaped into rectangular spots having a given size.

Spot images of the light beams B1' and B2' are formed, as spots of beams B1" and B2" having a given size, on a photosensitive member 20 which is a scanned surface via a scan lens 17, a mirror 18 and a scan lens 19. As shown in Fig. 4, an interval P between adjacent scan lines formed by the beams B1" and B2" (a sub scan pitch) can be adjusted so as to be equal to the interline pitch in the recording density by controlling angle θ of rotary movement round the optical axis. The two lines formed by the beams B1" and B2" simultaneously scan the photosensitive member 18.

Figs. 6A and 6B show a variation of the first embodiment of the present invention. In the variation, each surface of the polygonal mirror 14 includes a reflection surface 14a that is smaller than each surface. In other words, the edges of the reflection surface 14a are shorter than those of each surface of the polygonal mirror 14. The remaining portion of each surface of the polygonal mirror 14 is a step-like portion 14b, which may be formed by rounding. The step-like portion 14b has a comparatively low reflection rate and a comparatively rough surface. Alternatively, the

reflection surface 14 may be formed by bonding a mask or may be formed by an evaporation process in which only a reflection surface expected area is subjected to evaporation.

5 A description will now be given, with reference to Fig. 7, of a second embodiment of the present invention, which includes a light source 23 having a semiconductor laser diode array 22 in which two light-emitting sources 21a and 21b are formed in a
10 monolithic fashion. Fig. 7 is a cross-sectional view of the light source 23 taken along the main scan direction Y. Parts that are the same as those shown in the previously described figures are given the same reference numbers.

15 The semiconductor laser diode array 22 is inserted, with a pressure, into a fitting hole 24a formed on the back side of a base member 24 made of aluminum die-cast so that the light-emitting sources 21a and 21b are arranged in the main scan direction Y. The
20 light-emitting sources 21a and 21b have a size of approximately 100 μ m. A Coupling lens 25 is fixed to a supporting portion 24a by UV hardening resin, and is positioned as follows. That is, the coupling lens 25 is positioned in the X direction so that the light beams
25 emitted by the light-emitting sources 21a and 21b are

changed to light beams having a given divergence. The coupling lens 25 is positioned in the Y and Z directions so that the light-emitting sources 21a and 21b are positioned symmetrically with respect to the optical
5 axes of the coupling lens 25.

The light beams passing through the coupling lens 25 travel in an eccentric fashion in which the light beams do not travel on the optical axis C. Thus, the light beams cross each other at the focal position
10 of the coupling lens 25, and then diverge therefrom. A convergent lens 26 causes the diverging beams to cross each other again on each reflection surface 27a of a polygonal mirror 27.

The size of the light beams obtained at the
15 second crossing position is made larger than the size of each reflection surface 27a of the polygonal mirror 27 in order to cause the light beams reflected by the polygonal mirror 27 to have a given size, as in the case of the first embodiment of the present invention. The
20 base member 24 is fixed to the holding member 28 by means of screws, so that the pitch adjustment is implemented by adjustment of rotary movement round the optical axis.

A description will be given, with reference to
25 Fig. 8, of a third embodiment of the present invention.

Fig. 8 is a cross-sectional view of a light source of a multibeam scanning apparatus taken along the main scan direction Y. The light source includes two semiconductor laser diodes 701 and 702, which are
5 inserted, with a pressure, into fitting holes formed on the back side of a base member 703 made of aluminum die-cast and arranged side by side in the main scan direction Y. Two coupling lenses 704 and 705 are fixed to opposing surfaces of a projection 703-1 serving as a
10 support member by UV hardening resin. The coupling lenses 704 and 705 are positioned in the X direction so that the light beams emitted by the laser diodes 701 and 702 are changed to light beams having a given divergence. Further, the coupling lenses 704 and 705 are positioned
15 in the Y and Z directions so that the light beams travel in predetermined directions.

The coupling lenses 704 and 705 are positioned in an eccentric fashion with respect to the optical axis C in the main scan direction, so that the light beams go
20 out of the coupling lenses 704 and 705 at given angles.

The outgoing beam of the laser diode 701 passes through a beam combining unit 706, which is made up of a triangular prism and a parallelogram prism, these prisms being joined as shown in Fig. 8. The
25 outgoing beam of the laser diode 702 is reflected by a

slant surface 706-2 and a junction surface 706-1 in this order, and travels in the outgoing beam direction of the semiconductor laser diode 701. The semiconductor laser diodes 701 and 702 are positioned symmetrically with
5 respect to the optical axis C so that they are spaced apart from each other in the main scan direction at a given equal distance. The outgoing beam directions of the semiconductor laser diodes 701 and 702 are selected so that the light beams emitted therefrom cross each
10 other in the vicinity of the polygonal mirror.

The base member 703 is fixed to a holding member 707 by screws, and the pitch adjustment is implemented by adjustment of rotary movement round the optical axis, as has been described previously.

15 Fig. 9 shows a fourth embodiment of the present invention in which a cubic beam splitter 810 receives light beams emitted by semiconductor laser diodes 801 and 802 in different directions which form a right angle.

20 The semiconductor laser diodes 801 and 802 are inserted, with a pressure, into fitting holes formed in base members 803 and 804 made of aluminum die-cast. The base members 803 and 804 are supported by attachment surfaces 805-1 and 805-2 of a flange member 805
25 orthogonal to each other. The flange member 805 is made

of the same material as that of the base members 803 and 804. Two coupling lenses 808 and 809 are positioned in the X direction so that the outgoing beams of the semiconductor laser diodes 801 and 802 are changed to
5 light beams having a given divergence, and are then fixed to projections 803-1 and 804-1 serving as support members by UV hardening resin. The base members 803 and 804 are positioned in the Y and Z directions so that given outgoing beam directions can be obtained, and are
10 then fixed by screws.

The light-emitting points of the semiconductor laser diodes 801 and 802 are placed on the axes of the coupling lenses 808 and 809, and are spaced apart from each other at a given distance in the main scan
15 direction. A convergent lens system including convergent lenses 806-1 and 806-2 causes the light beams to cross each other between the lenses 806-1 and 806-2 and further cross each other in the vicinity of the polygonal mirror. The convergent lens 806-1 is
20 incorporated into the holding member 807, whereas the convergent lens 806-2 is provided separately from the light source.

A flange member 805 is fixed to the holding member 807 by screws, and the pitch adjustment is
25 implemented by adjustment of rotary movement round the

optical axis, as has been described previously.

The semiconductor laser diodes 801 and 802 may be disposed symmetrically with respect to the optical axis C so that they are spaced apart from each other at a given distance in the main scan direction. Instead of the crossing between the convergent lenses 806-1 and 806-2, it is possible to cross the light beams anywhere between the coupling lenses 808 and 809 and the convergent lens 806-1. The convergent lens system may consists of only one lens.

As has been described previously, there is no limitation on the number of times that the light beams cross each other. An aperture may be provided on the optical path between the light source and the polygonal mirror and may be located as close to the polygonal mirror (the reflection surfaces in the embodiments) as possible. Such an aperture makes it possible to control the relationship between the two beams and the central position. Thus, there is no possibility that the pitch adjustment may cause a deviation.

In the aforementioned embodiments of the present invention, the pitch adjustment is implemented by rotary movement of the light source. Thus, the semiconductor laser diodes, and the beam combining unit are incorporated into the light source. However, the

present invention is not limited to the above structure. For example, the pitch adjustment is accomplished by a structure in which one of the two optical axes may be slightly tilted in the sub scan direction with respect
5 to the other optical axis. The separate support will provide the same advantages.

In a synchronous detection for detecting the write initiation timings of the individual beams, only a single synchronous detection sensor can be used because
10 the beams pass through the sensor in time series.

The present invention is not limited to applications using two beams, but includes applications using three beams or more.

According to the present invention, the
15 outgoing beam directions of a plurality of light beams are selected so that the light beams substantially cross one another at a single point by means of the light source. Further, the light beams restricting means is provided in the vicinity of the beam crossing point.
20 Thus, the beam crossing point is located on the optical axis (rotational axis), and the positions of the optical beams are not changed even by rotating the light source for adjustment of the sub scan pitch. In addition, the desired spot size of the light beams can be obtained
25 without an inclination. It is therefore possible to

adjust the positions of the semiconductor laser diodes and the coupling lenses with a precision lower than that required in the conventional arrangements and to produce less-expensive multibeam scanning apparatuses

5 efficiently.

According to the present invention, a plurality of light-emitting sources of a semiconductor laser array are arranged in the main scan direction, and convergent means having at least a convergent function
10 in the main scan direction. Further, light beam restricting means for shaping the light beams into spots of a given size is arranged in the vicinity of the crossing point at which the beams cross each other. Hence, the positions of the light beams are not changed
15 even by rotating the light source for adjustment of the sub scan pitch. In addition, the desired spot size of the light beams can be obtained without an inclination. It is therefore possible to produce less-expensive multibeam scanning apparatuses efficiently.

20 According to the present invention, the polygonal mirror receives the spots of the beams having a size larger than the size of each reflection surface of the polygonal mirror. Further, each reflection surface of the polygonal mirror is formed so as to serve
25 as light beam restricting means. Thus, the size of each

reflection surface is equal to the effective size of the light beams, and each reflection surface can be reduced. This results in down sizing of the polygonal mirror and reduction in the load thereon. As a result, the
5 polygonal mirror may rotate at a higher rate, so that a higher rate, higher recording density multibeam scanning apparatus can be provided.

According to the present invention, each reflection surface of the polygonal mirror has an edge
10 shorter than that of each surface of the polygonal mirror. Thus, it is possible to avoid degradation of the precision in forming the surfaces resulting from an unevenness of an edge portion of the reflection surfaces and to reduce a difference in size among the reflection
15 surfaces due to a difference in the dividing angle of the reflection surfaces and a difference in the distance from the center of rotation. Thus, the desired beam spot size can be reliably obtained, so that high quality image recording can be accomplished. Even if the spot
20 size is reduced in the sub scan direction, a sufficient thickness of the polygon mirror can be ensured and rigidity cannot be degraded.

According to the present invention, the light beams from the light source are changed to light beams
25 having a given divergence. Thus, even when an optical

correction system is configured in which the polygonal mirror and the imaging surface have a conjugate relationship in terms of geometrical optics, it is possible to deviate the waist position of the light beams from the reflection surfaces and to thus restrict the spot sizes precisely while keeping the sufficient size of the reflection surfaces. Thus, the desired beam spots can be obtained reliably, and highly reliable image recording can be realized.

10 According to the present invention, a plurality of single-beam laser diodes or a laser diode array are arranged in the main scan direction, and the optical axes of the beams are controlled to directly cross each other or through optical means such as a mirror and a lens having a curvature in the main scan direction. An aperture is arranged in the vicinity of the cross point. If the beams are away from each other on the reflection surfaces of the polygonal mirror, it will be necessary to enlarge each reflection surface.

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20 However, this can be avoided when the polygonal mirror has reflection surfaces on which the function of the aperture is available (an over-field optical system).

 The present invention is not limited to the specifically disclosed embodiments, and variations and modifications may be made without departing from the

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scope of the present invention.

WHAT IS CLAIMED IS:

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1. A multibeam scan apparatus comprising:
 - a light source having semiconductor laser diodes and coupling lenses arranged in a main scan direction, the semiconductor laser diodes being
 - 10 positioned so that light beams emitted by the semiconductor laser diodes substantially cross each other at a point;
 - a light beam restricting unit shaping the light beams from the laser diodes through the coupling
 - 15 lenses so that the light beams have a given spot size, the light beam restricting unit being positioned close to the point;
 - a polygonal mirror; and
 - a scan lens causing the light beams reflected
 - 20 by the polygonal mirror to form images on a scanned surface.

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2. The multibeam scan apparatus as claimed in claim 1, wherein:

the light beam restricting unit is incorporated into each of reflection surfaces of the polygonal mirror; and

the spot size of the light beams incident to the polygonal mirror is larger than a size of each of the reflection surfaces in at least the main scan direction.

10

3. The multibeam scan apparatus as claimed in claim 2, wherein each of the reflection surfaces of the polygonal mirror has an edge shorter than surfaces of the polygonal mirror in which the reflection surfaces are formed.

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4. The multibeam scan apparatus as claimed in claim 1, wherein the coupling lenses change the light beams to those having a divergence.

25

5. A multibeam scan apparatus comprising:

a light source having a semiconductor laser diode array of light-emitting sources, and a coupling lens, the light-emitting sources being arranged in a

5 main scan direction;

a convergent unit causing the light beams to converge in the main scan direction;

a light beam restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close to a position at which the light beams cross each other due to a function of the convergent unit;

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a polygonal mirror; and

a scan lens causing the light beams reflected by the polygonal mirror to form images on a scanned surface.

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6. The multibeam scan apparatus as claimed in claim 5, wherein:

the light beam restricting unit is incorporated into each of reflection surfaces of the polygonal mirror; and

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the spot size of the light beams incident to the polygonal mirror is larger than a size of each of the reflection surfaces in at least the main scan direction.

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7. The multibeam scan apparatus as claimed in claim 6, wherein each of the reflection surfaces of the polygonal mirror has an edge shorter than surfaces of the polygonal mirror in which the reflection surfaces are formed.

15

8. The multibeam scan apparatus as claimed in claim 5, wherein the coupling lens changes the light beams to those having a divergence.

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9. A multibeam scan apparatus comprising:

a light source emitting light beams, outgoing beam directions in which the light beams travel being arranged so as to cross each other;

a deflection unit deflecting the light beams;

5 and

an optical unit causing the light beams from the deflection unit to form images on a scanned surface.

10

10. The multibeam scan apparatus as claimed in claim 9, wherein the light beams emitted by the light source cross each other at a position close to the

15 deflection unit.

20

11. The multibeam scan apparatus as claimed in claim 10, further comprising a light beam restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close to said position.

25

12. The multibeam scan apparatus as claimed
in claim 11, wherein the light beams cross each other on
a deflection surface of the deflection unit.

5

13. The multibeam scan apparatus as claimed
in claim 9, further comprising a light beam restricting
10 unit shaping the light beams so as to have a given spot
size, the light beam restricting unit being positioned
close to a position at which the light beams cross each
other.

15

14. The multibeam scan apparatus as claimed
in claim 11, wherein the light beam restricting unit is
20 incorporated into deflection surfaces of the deflection
unit, and the given spot size of the light beams is
larger than a size of each of the deflection surfaces.

25

15. The multibeam scan apparatus as claimed
in claim 13, wherein the light beam restricting unit is
incorporated into deflection surfaces of the deflection
unit, and the given spot size of the light beams is
5 larger than a size of each of the deflection surfaces.

10 16. The multibeam scan apparatus as claimed
in claim 14, wherein each of the deflection surfaces of
the deflection unit has an edge shorter than surfaces of
the deflection unit in which the deflection surfaces are
formed.

15

17. The multibeam scan apparatus as claimed
20 in claim 15, wherein each of the deflection surfaces of
the deflection unit has an edge shorter than surfaces of
the deflection unit in which the deflection surfaces are
formed.

25

18. A multibeam scan apparatus comprising:
a light source having semiconductor laser
diodes and coupling lenses arranged in a main scan
direction, the semiconductor laser diodes being
5 positioned so that outgoing beam directions in which
light beams emitted by the semiconductor laser diodes
travel cross each;
a deflection unit deflecting the light beams;
and
10 an optical unit causing the light beams to
form images on a scanned surface.

15 19. The multibeam scan apparatus as claimed
in claim 18, wherein the light beams cross each other at
a position close to the deflection unit.

20 20. The multibeam scan apparatus as claimed
in claim 19, further comprising a light beam restricting
25 unit shaping the light beams so as to have a given spot

size, the light beam restricting unit being positioned close to said position.

5

21. The multibeam scan apparatus as claimed in claim 20, wherein the light beams cross each other on a deflection surface of the deflection unit.

10

22. The multibeam scan apparatus as claimed in claim 18, further comprising a light beam restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close to a position at which the light beams cross each other.

20

23. The multibeam scan apparatus as claimed in claim 20, wherein the light beam restricting unit is

25

incorporated into deflection surfaces of the deflection unit, and the given spot size of the light beams is larger than a size of each of the deflection surfaces.

5

24. The multibeam scan apparatus as claimed in claim 22, wherein the light beam restricting unit is
10 incorporated into deflection surfaces of the deflection unit, and the given spot size of the light beams is larger than a size of each of the deflection surfaces.

15

25. The multibeam scan apparatus as claimed in claim 23, wherein each of the deflection surfaces of the deflection unit has an edge shorter than surfaces of
20 the deflection unit in which the deflection surfaces are formed.

25

26. The multibeam scan apparatus as claimed
in claim 24, wherein each of the deflection surfaces of
the deflection unit has an edge shorter than surfaces of
the deflection unit in which the deflection surfaces are
5 formed.

10 27. A multibeam scan apparatus comprising:
a light source having a semiconductor laser
diode array of light-emitting sources formed in a
monolithic formation, and a coupling lens, the light-
emitting sources being arranged in a main scan
15 direction;
a convergent unit causing the light beams to
converge in the main scan direction;
a light beam restricting unit shaping the
light beams so as to have a given spot size, the light
20 beam restricting unit being positioned close to a
position at which the light beams cross each other due
to a function of the convergent unit;
a deflection unit deflecting the light beams;
and
25 a scan lens causing the light beams deflected

by the deflection unit to form images on a scanned surface.

5

28. The multibeam scan apparatus as claimed in claim 27, further comprising a light beam restricting unit shaping the light beams so as to have a given spot size, the light beam restricting unit being positioned close to said position.

15

29. The multibeam scan apparatus as claimed in claim 27 wherein:

the light beam restricting unit is incorporated into each of deflection surfaces of the deflection unit; and

20

the spot size of the light beams incident to the deflection unit is larger than a size of each of the deflection surfaces in at least the main scan direction.

25

30. The multibeam scan apparatus as claimed
in claim 29, wherein each of the deflection surfaces of
the deflection unit has an edge shorter than surfaces of
the deflection unit in which the deflection surfaces are
5 formed.

10 31. The multibeam scan apparatus as claimed
in claim 30, wherein the coupling lens changes the light
beams to those having a divergence.

ABSTRACT OF THE DISCLOSURE

A multibeam scan apparatus includes a light source having semiconductor laser diodes and coupling lenses arranged in a main scan direction. The

5 semiconductor laser diodes are positioned so that light beams emitted by the semiconductor laser diodes substantially cross each other at a point. A light beam restricting unit shapes the light beams from the laser diodes through the coupling lenses so that the light

10 beams have a given spot size. The light beam restricting unit is positioned close to the above-mentioned point. A scan lens causes the light beams reflected by a polygonal mirror to form images on a scanned surface.

15

FIG. 1

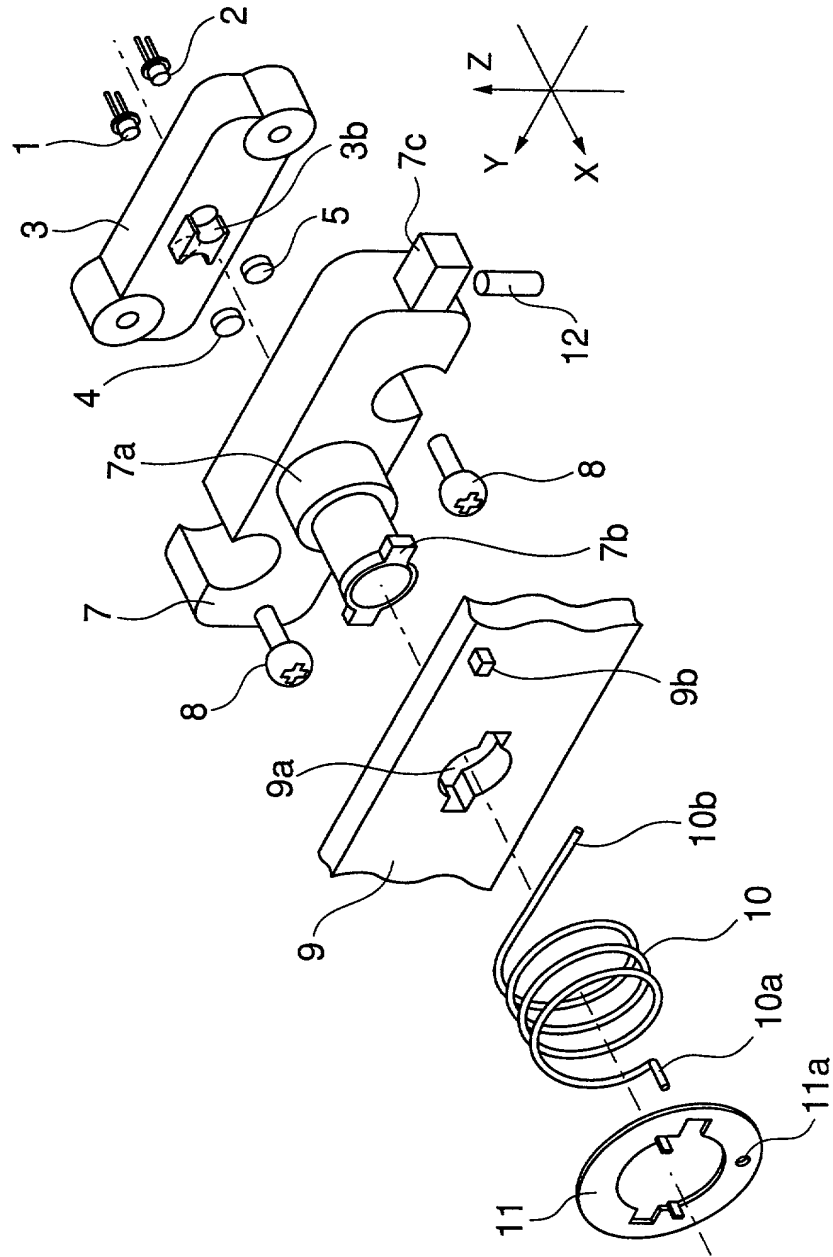


FIG. 2

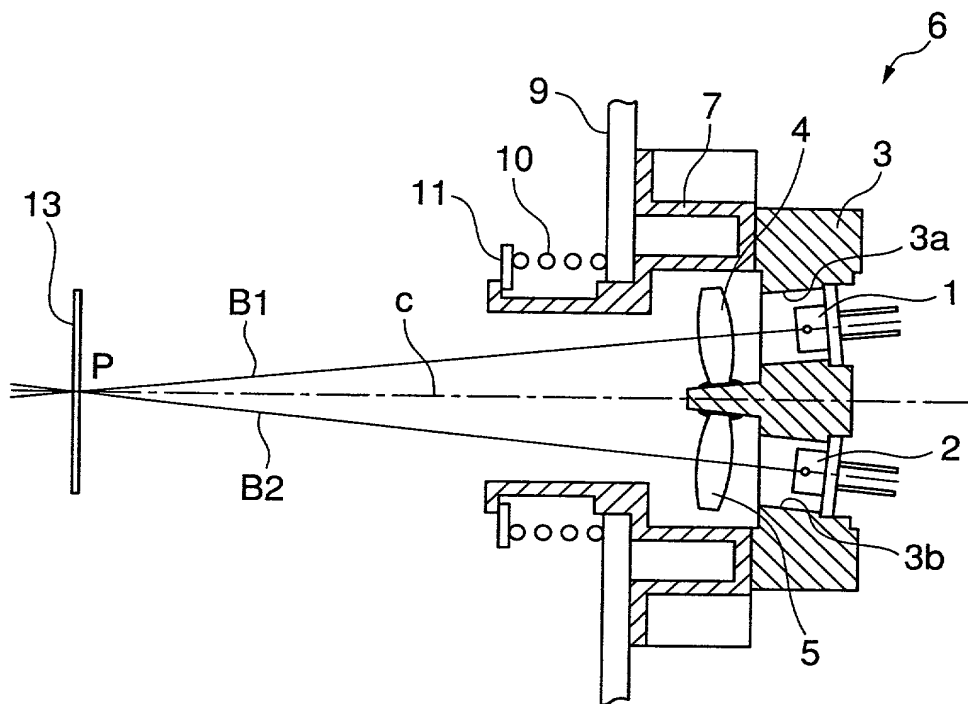


FIG. 3

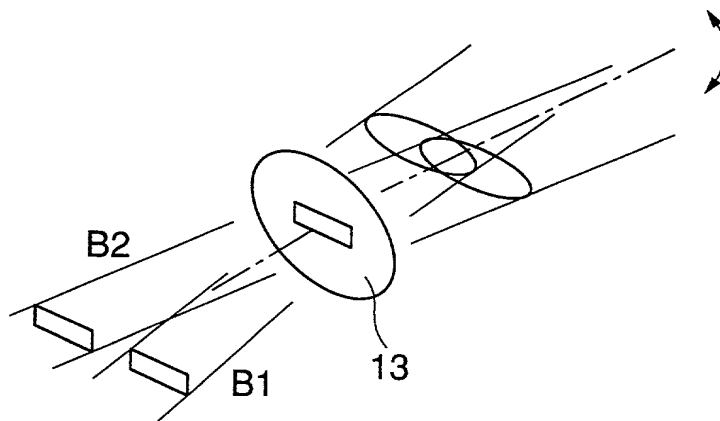


FIG. 4

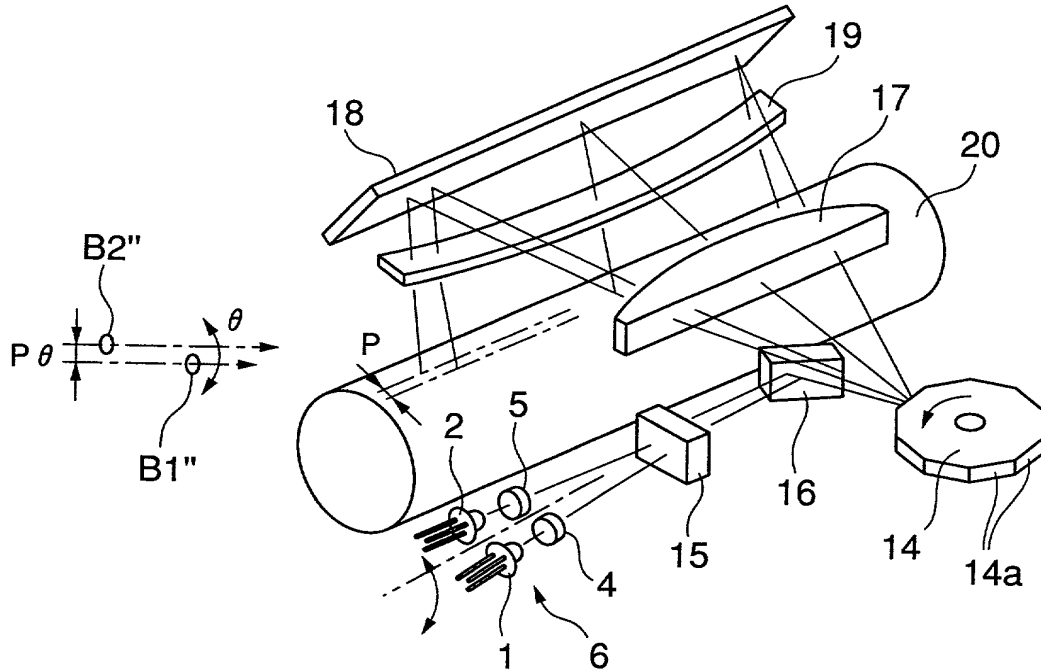


FIG. 5A

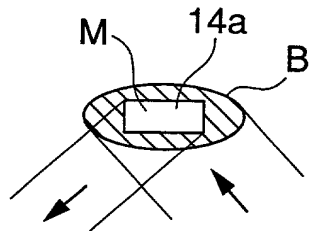


FIG. 5B

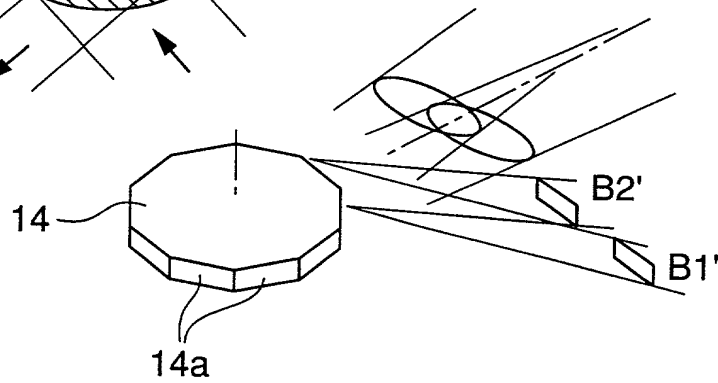


FIG. 6A

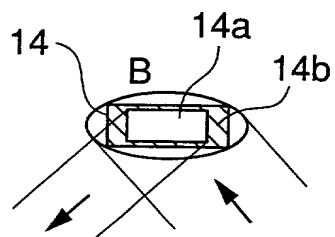


FIG. 6B

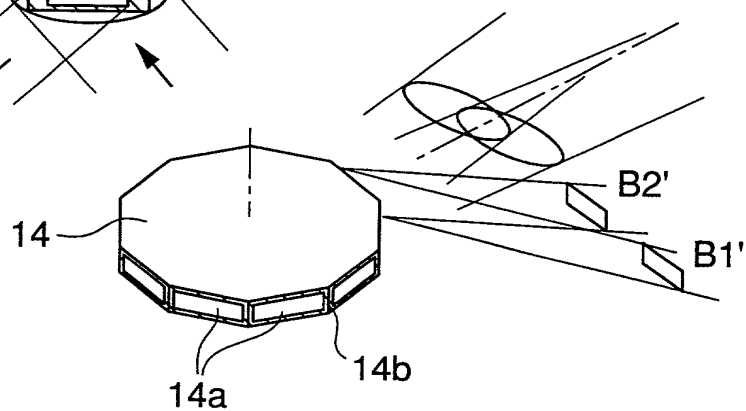


FIG. 7

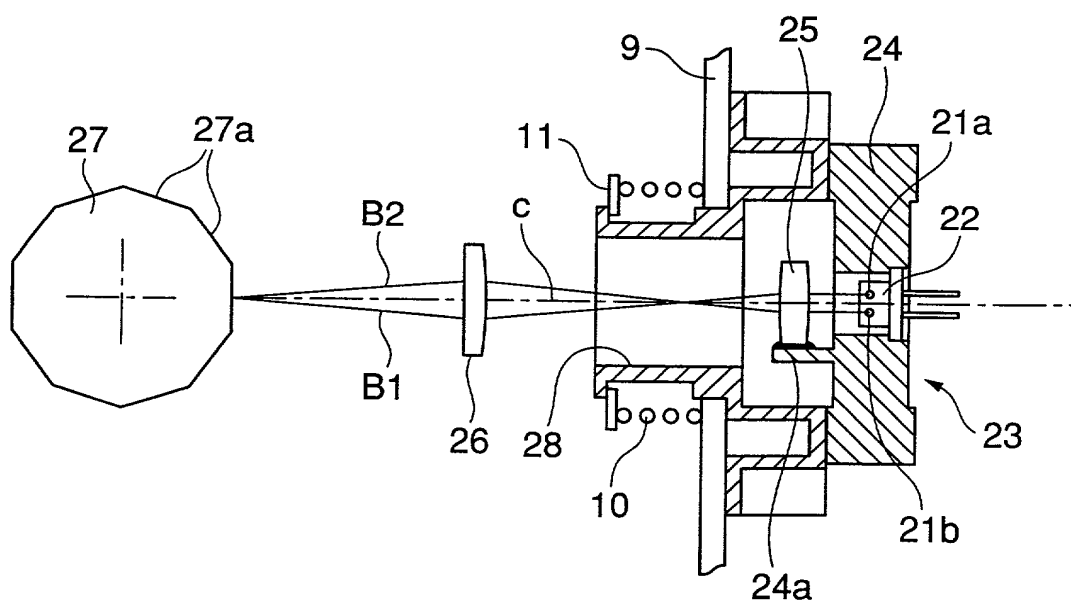


FIG. 8

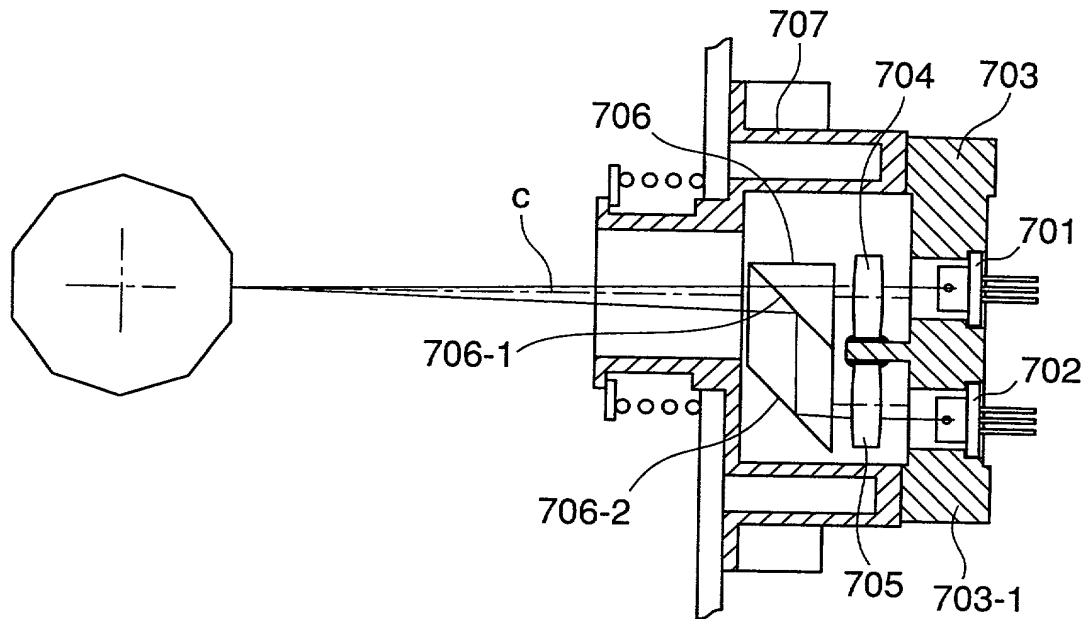


FIG. 9

